IRFB33N15DPBF

IRFB33N15DPBF Information

For Reference Only

Part Number IRFB33N15DPBF
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Single
Description MOSFET N-CH 150V 33A TO-220AB
Package TO-220-3

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

IRFB33N15DPBF Specifications

Manufacturer Part Number	IRFB33N15DPBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	150V
Current - Continuous Drain (Id) @ 25°C	33A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	90nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2020pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	3.8W (Ta), 170W (Tc)
Rds On (Max) @ Id, Vgs	56 mOhm @ 20A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IRFB33N15DPBF Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFB33N15DPBF Payment Methods

IRFB33N15DPBF Shipping Methods

If you have any question about IRFB33N15DPBF, please do not hesitate to contact us!
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